

1550 DFB 1.25G Laser Diode With LC TOSA

Data Sheet

OLD3358-C1-LTO

Features

- Uncooled
- Type C laser
- Low threshold current
- Power Output: 2 mW
- 1550nm InGaAsP/ InP MQW-DFB laser diode
- High speed InGaAs monitor PIN photodiode
- Packaged in LC TOSA with fiber stub
- Operating Temperature: 0 ~ +70°C

Applications

- Digital Signal Transmission
- Telecommunications (Local loop, interoffice and intraoffice)
- Data Communications
- SONET OC-3, OC-12, OC-24/SDH STM-1, STM-4, STM-8
- Gigabit Ethernet
- Fiber Channel

Description

The OLD3358-C1-LTO is a hermetically sealed InGaAsP/ InP DFB laser diode module in a small TOSA type package, including a high speed InGaAs PIN monitor photodiode and packaged in LC TOSA with fiber stub.

The laser diode is designed for use in data communications systems and telecommunications systems over singlemode fiber, and can operate in temperatures of 0°C to +70°C. The laser diode module transmits emission power to the monitor photodiode in the rear, which ensures highly stable emission at a wavelength of 1550 nm.

Safety

Radiation emitted by laser diode devices can be dangerous to the eyes. Avoid direct or scattered radiation exposure to the eyes or skin. Device contains gallium arsenide (GaAs) which can be hazardous to your health. Please embrace all customary precautions and discretion while handling this device. Observe governmental laws and regulations when discarding this device.

Performance Specifications

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause damage to the optical device. Operations of the optical device are suggested to remain within the recommended operating conditions. Exposure to the absolute maximum ratings for extended periods can adversely affect device reliability.

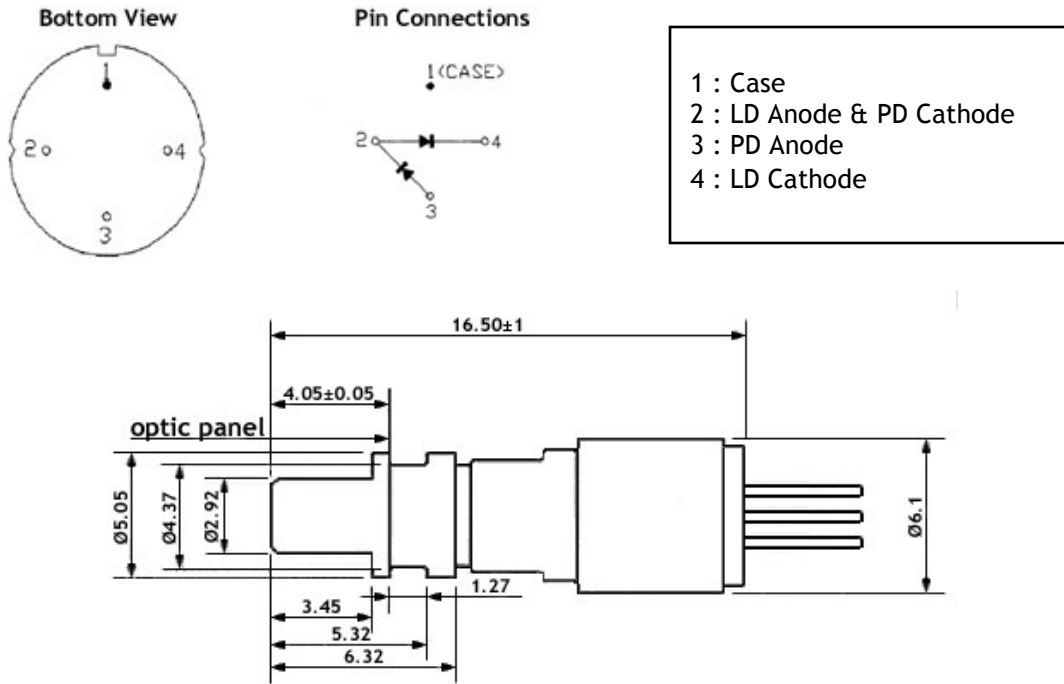
Parameter	Symbol	Value	Unit
Storage Temperature	T_{stg}	-40 to +85	°C
Operating Case Temperature	T_{op}	0 to +70	°C
Peak Optical Output Power	P_o	4	mW
Forward Current (LD)	I_{FLD}	150	mA
Reverse Voltage (LD)	V_{RLD}	2	V
Reverse Current (PD)	I_{RPD}	2	mA
Reverse Voltage (PD)	V_{RPD}	15	V
Soldering Temperature	S_{temp}	260	°C
Soldering Time	S_{time}	10	sec

Electrical and Optical Characteristics ($T_C=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Threshold Current	I_{th}	CW	-	10	20	mA
		CW, $T_C=0-70^\circ\text{C}$	-	-	50	
Operating Voltage	V_{op}	CW, Pop, $T_C=0-70^\circ\text{C}$	-	1.2	1.6	V
Operating Current	I_{op}	Pop=2.0mW	-	35	45	mA
Peak Wavelength	λ_p	CW, Pop	1530	-	1570	nm
Side-mode Suppression Ratio	SMSR	CW, Pop, $T_C=0-70^\circ\text{C}$	30	40	-	dB
Rise Time	T_r	$I_b=I_{th}$, 20%-80%	-	-	0.10	ns
Fall Time	T_f	$I_b=I_{th}$, 20%-80%	-	-	0.15	ns
Monitor Current	I_m	Pop, $V_{rp}=5V$	0.15	0.6	-	mA
Monitor Dark Current	I_d	$V_{rp}=5V$	-	-	10	nA
		$V_{rp}=5V$, $T_C=0-70^\circ\text{C}$	-	-	100	
Monitor Capacitance	C	$V_{rp}=5V$, $f=1\text{MHz}$	-	-	10	pF
Tracking Error	-	APC, 0 to +70° C	-	±0.7	±1.5	dB

Package Outline Diagram

Dimensions for the device package are given in millimeters.



Additional Information

Contact

For additional information, product specifications, or information about Optocom:

Internet: <http://www.optocom.com>

Email: sales@optocom.com

Tel: +1 978 988 8711

Fax: +1 978 988 8722

©2005 Optocom Corporation. All rights reserved. Information in this document is believed to be accurate and reliable and is subject to change without notice. Optocom Corporation will not be held liable for technical or editorial errors or omissions contained herein. Reproduction in whole or in part is prohibited without prior written consent of the copyright owner and no responsibility will be assumed by Optocom Corporation for any infringements of third parties. All other brand or product names mentioned are the trademarks or registered trademarks owned by their respective companies or organizations.